## FEATURES

Low Noise $6 \mathrm{nV} / \sqrt{\mathrm{Hz}}$
Low Offset Voltage: $100 \mu \mathrm{~V}$ Max
Low Input Bias Current 10 pA Max
Fast Settling: 600 ns to 0.01\%
Low Distortion
Unity Gain Stable
No Phase Reversal
Dual-Supply Operation: $\pm 5 \mathrm{~V}$ to $\pm 13 \mathrm{~V}$
APPLICATIONS
Photodiode Amplifier
ATE
Instrumentation
Sensors and Controls
High Performance Filters
Fast Precision Integrators
High Performance Audio

## FUNCTIONAL BLOCK DIAGRAMS

8-Lead MSOP and SOIC
(RM-8 and R-8 Suffixes)


NC = NO CONNECT
8-Lead SOIC
(R-8 Suffix)


## GENERAL DESCRIPTION

The AD8610/AD8620 is a very high precision JFET input amplifier featuring ultralow offset voltage and drift, very low input voltage and current noise, very low input bias current, and wide bandwidth. Unlike many JFET amplifiers, the AD8610/AD8620 input bias current is low over the entire operating temperature range. The AD8610/AD8620 is stable with capacitive loads of over 1000 pF in noninverting unity gain; much larger capacitive loads can be driven easily at higher noise gains. The AD8610/AD8620 swings to within 1.2 V of the supplies even with a $1 \mathrm{k} \Omega$ load, maximizing dynamic range even with limited supply voltages. Outputs slew at $50 \mathrm{~V} / \mu \mathrm{s}$ in either inverting or noninverting gain configurations, and settle to $0.01 \%$ accuracy in less than 600 ns . Combined with the high input impedance, great precision, and very high output drive, the

REV. D

AD8610/AD8620 is an ideal amplifier for driving high performance $\mathrm{A} / \mathrm{D}$ inputs and buffering $\mathrm{D} / \mathrm{A}$ converter outputs.
Applications for the AD8610/AD8620 include electronic instruments; ATE amplification, buffering, and integrator circuits; CAT/MRI/ultrasound medical instrumentation; instrumentation quality photodiode amplification; fast precision filters (including PLL filters); and high quality audio.
The AD8610/AD8620 is fully specified over the extended industrial $\left(-40^{\circ} \mathrm{C}\right.$ to $\left.+125^{\circ} \mathrm{C}\right)$ temperature range. The AD8610 is available in the narrow 8-lead SOIC and the tiny MSOP8 surface-mount packages. The AD8620 is available in the narrow 8-lead SOIC package. MSOP8 packaged devices are available only in tape and reel.

## AD8610/AD8620-SPECIFICATIONS

(@ $\mathrm{V}_{\mathrm{S}}= \pm 5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted.)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT CHARACTERISTICS |  |  |  |  |  |  |
|  | $\mathrm{V}_{\text {OS }}$ | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | 80 | 200 | $\mu \mathrm{V}$ |
| Offset Voltage (AD8620B) | $\mathrm{V}_{\text {OS }}$ |  |  | 45 | 150 | $\mu \mathrm{V}$ |
| Offset Voltage (AD8610A/AD8620A) |  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | 80 | 300 | $\mu \mathrm{V}$ |
|  | $\mathrm{V}_{\text {OS }}$ |  |  | 85 | 250 | $\mu \mathrm{V}$ |
|  |  | $+25^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<125^{\circ} \mathrm{C}$ |  | 90 | 350 | $\mu \mathrm{V}$ |
| Input Bias Current | $\mathrm{I}_{\mathrm{B}}$ | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | 150 | 850 | $\mu \mathrm{V}$ |
|  |  |  | -10 | +2 | +10 | $\mathrm{pA}$ |
| Input Offset Current |  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | -250 | +130 | +250 | pA |
|  |  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | -2.5 | +1.5 | +2.5 | nA |
|  | $\mathrm{I}_{\mathrm{OS}}$ |  | -10 | +1 | +10 | pA |
|  |  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+85^{\circ} \mathrm{C}$ | -75 | +20 | +75 | pA |
|  |  | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | -150 | +40 | +150 | pA |
| Input Voltage Range |  |  | -2 |  | +3 | V |
| Common-Mode Rejection Ratio | CMRR | $\mathrm{V}_{\mathrm{CM}}=-2.5 \mathrm{~V}$ to +1.5 V | 90 | 95 |  | dB |
| Large Signal Voltage Gain | $\mathrm{A}_{\mathrm{Vo}}$ | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{V}_{\mathrm{O}}=-3 \mathrm{~V}$ to +3 V | 100 | 180 |  | $\mathrm{V} / \mathrm{mV}$ |
| Offset Voltage Drift (AD8610B) | $\Delta \mathrm{V}_{\text {OS }} / \Delta \mathrm{T}$ | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | 0.5 | 1 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Offset Voltage Drift (AD8620B) | $\Delta \mathrm{V}_{\mathrm{OS}} / \Delta \mathrm{T}$ | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | 0.5 | 1.5 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Offset Voltage Drift (AD8610A/AD8620A) | $\Delta \mathrm{V}_{\mathrm{OS}} / \Delta \mathrm{T}$ | $-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | 0.8 | 3.5 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |  |
| Output Voltage High | $\mathrm{V}_{\mathrm{OH}}$ | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega,-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ | 3.8 |  |  |  |
| Output Voltage Low | $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega,-40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C}$ |  | $\begin{aligned} & -4 \\ & +30 \end{aligned}$ | -3.8 | V |
| POWER SUPPLY |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |
| Power Supply Rejection Ratio | PSRR <br> $\mathrm{I}_{\mathrm{SY}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}= \pm 5 \mathrm{~V} \text { to } \pm 13 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{O}}=0 \mathrm{~V} \\ & -40^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{A}}<+125^{\circ} \mathrm{C} \end{aligned}$ | 100 | 110 |  | dB |
| Supply Current/Amplifier |  |  |  | 2.5 | 3.0 | mA |
|  |  |  |  | 3.0 | 3.5 | mA |
| DYNAMIC PERFORMANCE |  |  |  |  |  |  |
| Slew Rate | SR | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | 40 | 50 |  | V/ $\mu \mathrm{s}$ |
| Gain Bandwidth Product | GBP |  |  | 25 |  | MHz |
| Settling Time | $\mathrm{t}_{\text {S }}$ | $\mathrm{A}_{\mathrm{V}}=+1,4 \mathrm{~V}$ Step, to $0.01 \%$ |  | 350 |  | ns |
| NOISE PERFORMANCE |  |  |  |  |  |  |
| Voltage Noise | $\mathrm{e}_{\mathrm{n}} \mathrm{p}-\mathrm{p}$ | 0.1 Hz to 10 Hz |  | 1.8 |  | $\mu \mathrm{V}$ p-p |
| Voltage Noise Density | $\mathrm{e}_{\mathrm{n}}$ | $\mathrm{f}=1 \mathrm{kHz}$ |  | 6 |  | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
| Current Noise Density | $\mathrm{i}_{\mathrm{n}}$ | $\mathrm{f}=1 \mathrm{kHz}$ |  | 5 |  | $\mathrm{fA} / \sqrt{\mathrm{Hz}}$ |
| Input Capacitance | $\mathrm{C}_{\text {IN }}$ |  |  |  |  |  |
| Differential |  |  |  | 8 |  | pF |
| Common-Mode |  |  |  | 15 |  | pF |
| Channel Separation | $\mathrm{C}_{\text {S }}$ |  |  |  |  |  |
| $\mathrm{f}=10 \mathrm{kHz}$ |  |  |  | 137 |  | dB |
| $\mathrm{f}=300 \mathrm{kHz}$ |  |  |  | 120 |  | dB |

[^0]
## ELECTRICAL SPECIFICATIONS ( $@ V_{S}= \pm 13, v_{c n}=0, V_{A}=25^{\circ}$, unless otherwise noted.)



[^1]
## AD8610/AD8620

ABSOLUTE MAXIMUM RATINGS*

|  |  |
| :---: | :---: |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |
|  |  |


| Package Type | $\boldsymbol{\theta}_{\mathrm{JA}}{ }^{\boldsymbol{*}}$ | $\boldsymbol{\theta}_{\mathrm{JC}}$ | Unit |
| :--- | :---: | :---: | :---: |
| 8-Lead MSOP (RM) | 190 | 44 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| 8-Lead SOIC (RN) | 158 | 43 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

${ }^{*} \theta_{\mathrm{JA}}$ is specified for worst-case conditions; i.e., $\theta_{\mathrm{JA}}$ is specified for a device soldered in circuit board for surface-mount packages.

| Model | Temperature <br> Range | Package <br> Description | Package <br> Option | Branding |
| :--- | :--- | :--- | :--- | :--- |
| AD8610AR | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610AR-REEL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610AR-REEL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 | BeA |
| AD8610ARM-REEL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead MSOP | RM-8 | B0A |
| AD8610ARM-R2 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead MSOP | RM-8 | B0A |
| AD8610ARZ* | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610ARZ-REEL* | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610ARZ-REEL7* | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610BR | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610BR-REEL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610BR-REEL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610BRZ* | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610BRZ-REEL* | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8610BRZ-REEL7* | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8620AR | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8620AR-REEL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8620AR-REEL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8620BR | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8620BR-REEL | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |
| AD8620BR-REEL7 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8-Lead SOIC | RN-8 |  |

[^2]
## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8610/AD8620 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.


## Typical Performance Characteristics-AD8610/AD8620



TPC 1. Input Offset Voltage at $\pm 13 \mathrm{~V}$


TPC 2. Input Offset Voltage vs. Temperature at $\pm 13$ V (300 Amplifiers)


TPC 5. Input Offset Voltage Drift


TPC 8. Supply Current vs.
Temperature at $\pm 13 \mathrm{~V}$


TPC 3. Input Offset Voltage at $\pm 5 \mathrm{~V}$


TPC 6. Input Bias Current vs. Common-Mode Voltage


TPC 9. Supply Current vs.
Temperature at $\pm 5 \mathrm{~V}$


TPC 10. Output Voltage to Supply Rail vs. Load


TPC 13. Output Voltage High vs. Temperature at $\pm 13 \mathrm{~V}$


TPC 16. Closed-Loop Gain vs. Frequency


TPC 11. Output Voltage High vs. Temperature at $\pm 5 \mathrm{~V}$


TPC 14. Output Voltage Low vs.
Temperature at $\pm 13 \mathrm{~V}$


TPC 17. $A_{V o}$ vs. Temperature at $\pm 13 \mathrm{~V}$


TPC 12. Output Voltage Low vs. Temperature at $\pm 5 \mathrm{~V}$


TPC 15. Open-Loop Gain and Phase vs. Frequency


TPC 18. $A_{v o}$ vs. Temperature at $\pm 5 \mathrm{~V}$



TPC 19. PSRR vs. Frequency at $\pm 13 \mathrm{~V}$


TPC 22. CMRR vs. Frequency


TPC 25. 0.1 Hz to 10 Hz Input Voltage Noise


TPC 20. PSRR vs. Frequency at $\pm 5 \mathrm{~V}$


TPC 23. Positive Overvoltage Recovery


TPC 26. Input Voltage Noise vs. Frequency


TPC 21. PSRR vs. Temperature


TPC 24. Negative Overvoltage Recovery


TPC 27. Zout vs. Frequency

## AD8610/AD8620



TPC 28. $Z_{\text {Out }}$ vs. Frequency


TPC 31. Small Signal Overshoot vs. Load Capacitance


TIME - 400ns/DIV
TPC 34. + SR at $G=+1$


TPC 29. Input Bias Current vs. Temperature


TIME $-400 \mu \mathrm{~s} /$ DIV

TPC 32. No Phase Reversal


TPC 35. - SR at $G=+1$


TPC 30. Small Signal Overshoot vs. Load Capacitance


TIME - $1 \mu \mathrm{~s} / \mathrm{DIV}$

TPC 33. Large Signal Response at G = +1


TIME - $1 \mu \mathrm{~s} / \mathrm{DIV}$
TPC 36. Large Signal Response at $G=-1$


TIME - 400ns/DIV
TPC 37. + SR at $G=-1$


TPC 38. $-S R$ at $G=-1$


Figure 2. AD8620 Channel Separation Graph

## Power Consumption

A major advantage of the AD8610/AD8620 in new designs is the saving of power. Lower power consumption of the AD8610 makes it much more attractive for portable instrumentation and for high-density systems, simplifying thermal management, and reducing power supply performance requirements. Compare the power consumption of the AD8610/AD8620 versus the OPA627 in Figure 3.


Figure 3. Supply Current vs. Temperature

## AD8610/AD8620

## Driving Large Capacitive Loads

The AD8610 has excellent capacitive load driving capability and can safely drive up to 10 nF when operating with $\pm 5 \mathrm{~V}$ supply. Figures 4 and 5 compare the AD8610/AD8620 against the OPA627 in the noninverting gain configuration driving a $10 \mathrm{k} \Omega$ resistor and $10,000 \mathrm{pF}$ capacitor placed in parallel on its output, with a square wave input set to a frequency of 200 kHz . The AD8610 has much less ringing than the OPA627 with heavy capacitive loads.


TIME $-2 \mu \mathrm{~S} /$ DIV
Figure 4. OPA627 Driving $C_{L}=10,000 \mathrm{pF}$


Figure 5. AD8610/AD8620 Driving $C_{L}=10,000 \mathrm{pF}$
The AD8610/AD8620 can drive much larger capacitances without any external compensation. Although the AD8610/AD8620 is stable with very large capacitive loads, remember that this capacitive loading will limit the bandwidth of the amplifier. Heavy capacitive loads will also increase the amount of overshoot and ringing at the output. Figures 7 and 8 show the AD8610/AD8620 and the OPA627 in a noninverting gain of +2 driving $2 \mu \mathrm{~F}$ of capacitance load. The ringing on the OPA627 is much larger in magnitude and continues more than 10 times longer than the AD 8610 .


Figure 6. Capacitive Load Drive Test Circuit


Figure 7. OPA627 Capacitive Load Drive, $A_{V}=+2$


Figure 8. AD8610/AD8620 Capacitive Load Drive, $A_{V}=+2$

## Slew Rate (Unity Gain Inverting vs. Noninverting)

Amplifiers generally have a faster slew rate in an inverting unity gain configuration due to the absence of the differential input capacitance. Figures 9 through 12 show the performance of the AD8610 configured in a gain of -1 compared to the OPA627. The AD8610 slew rate is more symmetrical, and both the positive and negative transitions are much cleaner than in the OPA627.


Figure 9. (+SR) of AD8610/AD8620 in Unity Gain of -1


Figure 10. (+SR) of OPA627 in Unity Gain of -1


Figure 11. (-SR) of AD8610/AD8620 in Unity Gain of -1


Figure 12. (-SR) of OPA627 in Unity Gain of -1
The AD8610 has a very fast slew rate of $60 \mathrm{~V} / \mu \mathrm{s}$ even when configured in a noninverting gain of +1 . This is the toughest condition to impose on any amplifier since the input common-mode capacitance of the amplifier generally makes its SR appear worse. The slew rate of an amplifier varies according to the voltage difference between its two inputs. To observe the maximum SR as specified in the AD8610 data sheet, a difference voltage of about 2 V between the inputs must be ensured. This will be required for virtually any JFET op amp so that one side of the op amp input circuit is completely off, maximizing the current available to charge and discharge the internal compensation capacitance. Lower differential drive voltages will produce lower slew rate readings. A JFETinput op amp with a slew rate of $60 \mathrm{~V} / \mu \mathrm{s}$ at unity gain with $\mathrm{V}_{\text {IN }}=10 \mathrm{~V}$ might slew at $20 \mathrm{~V} / \mu \mathrm{s}$ if it is operated at a gain of +100 with $\mathrm{V}_{\text {IN }}=100 \mathrm{mV}$.

The slew rate of the AD8610/AD8620 is double that of the OPA627 when configured in a unity gain of +1 (see Figures 13 and 14).


Figure 13. (+SR) of AD8610/AD8620 in Unity Gain of +1


Figure 14. (+SR) of OPA627 in Unity Gain of +1
The slew rate of an amplifier determines the maximum frequency at which it can respond to a large signal input. This frequency (known as full-power bandwidth, or FPBW) can be calculated from the equation:

$$
F P B W=\frac{S R}{\left(2 \pi \times V_{P E A K}\right)}
$$

for a given distortion (e.g., 1\%).


Figure 15. AD8610 FPBW

## Input Overvoltage Protection

When the input of an amplifier is driven below $\mathrm{V}_{\mathrm{EE}}$ or above $\mathrm{V}_{\mathrm{CC}}$ by more than one $\mathrm{V}_{\mathrm{BE}}$, large currents will flow from the substrate through the negative supply ( $\mathrm{V}-$ ) or the positive supply ( $\mathrm{V}+$ ), respectively, to the input pins, which can destroy the device. If the input source can deliver larger currents than the maximum forward current of the diode ( $>5 \mathrm{~mA}$ ), a series resistor can be added to protect the inputs. With its very low input bias and offset current, a large series resistor can be placed in front of the AD8610 inputs to limit current to below damaging levels. Series resistance of $10 \mathrm{k} \Omega$ will generate less than $25 \mu \mathrm{~V}$ of offset. This $10 \mathrm{k} \Omega$ will allow input voltages more than 5 V beyond either power supply. Thermal noise generated by the resistor will add $7.5 \mathrm{nV} / \sqrt{\mathrm{Hz}}$ to the noise of the AD8610. For the AD8610/AD8620, differential voltages equal to the supply voltage will not cause any problem (see Figure 15). In this context, it should also be noted that the high breakdown voltage of the input FETs eliminates the need to include clamp diodes between the inputs of the amplifier, a practice that is mandatory on many precision op amps. Unfortunately, clamp
diodes greatly interfere with many application circuits such as precision rectifiers and comparators. The AD8610 is free from these limitations.


Figure 16. Unity Gain Follower

## No Phase Reversal

Many amplifiers misbehave when one or both of the inputs are forced beyond the input common-mode voltage range. Phase reversal is typified by the transfer function of the amplifier, effectively reversing its transfer polarity. In some cases, this can cause lockup and even equipment damage in servo systems, and may cause permanent damage or nonrecoverable parameter shifts to the amplifier itself. Many amplifiers feature compensation circuitry to combat these effects, but some are only effective for the inverting input. The AD8610/AD8620 is designed to prevent phase reversal when one or both inputs are forced beyond their input common-mode voltage range.


Figure 17. No Phase Reversal

## THD Readings vs. Common-Mode Voltage

Total harmonic distortion of the AD8610/AD8620 is well below $0.0006 \%$ with any load down to $600 \Omega$. The AD8610/AD8620 outperforms the OPA627 for distortion, especially at frequencies above 20 kHz .


Figure 18. AD8610 vs. OPA627 THD + Noise @ $V_{C M}=0$ V


Figure 19. THD + Noise vs. Frequency
Noise vs. Common-Mode Voltage
AD8610 noise density varies only $10 \%$ over the input range as shown in Table I.

Table I. Noise vs. Common-Mode Voltage

| $\mathbf{V}_{\mathbf{C M}}$ at $\mathrm{F}=\mathbf{1 ~ \mathbf { ~ k H z } ( \mathrm { V } )}$ | Noise Reading $(\mathbf{n V} / \sqrt{\mathbf{H z}})$ |
| :--- | :--- |
| -10 | 7.21 |
| -5 | 6.89 |
| 0 | 6.73 |
| +5 | 6.41 |
| +10 | 7.21 |

## Settling Time

The AD8610 has a very fast settling time, even to a very tight error band, as can be seen from Figure 20. The AD8610 is configured in an inverting gain of +1 with $2 \mathrm{k} \Omega$ input and feedback resistors. The output is monitored with a $10 \times 10 \mathrm{M}, 11.2 \mathrm{pF}$ scope probe.


Figure 20. AD8610 Settling Time vs. Error Band


Figure 21. OPA627 Settling Time vs. Error Band
The AD8610/AD8620 maintains this fast settling when loaded with large capacitive loads as shown in Figure 22.


Figure 22. AD8610 Settling Time vs. Load Capacitance


Figure 23. OPA627 Settling Time vs. Load Capacitance

## Output Current Capability

The AD8610 can drive very heavy loads due to its high output current. It is capable of sourcing or sinking 45 mA at $\pm 10 \mathrm{~V}$ output. The short circuit current is quite high and the part is capable of sinking about 95 mA and sourcing over 60 mA while operating with

## AD8610/AD8620

supplies of $\pm 5 \mathrm{~V}$. Figures 24 and 25 compare the load current versus output voltage of AD8610/AD8620 and OPA627.


Figure 24. AD8610 Dropout from $\pm 13$ V vs. Load Current


Figure 25. OPA627 Dropout from $\pm 15$ V vs. Load Current
Although operating conditions imposed on the AD8610 ( $\pm 13 \mathrm{~V}$ ) are less favorable than the OPA627 ( $\pm 15 \mathrm{~V}$ ), it can be seen that the AD8610 has much better drive capability (lower headroom to the supply) for a given load current.
Operating with Supplies Greater than $\pm 13$ V
The AD8610 maximum operating voltage is specified at $\pm 13 \mathrm{~V}$. When $\pm 13 \mathrm{~V}$ is not readily available, an inexpensive LDO can provide $\pm 12 \mathrm{~V}$ from a nominal $\pm 15 \mathrm{~V}$ supply.

Input Offset Voltage Adjustment
Offset of AD8610 is very small and normally does not require additional offset adjustment. However, the offset adjust pins can be used as shown in Figure 26 to further reduce the dc offset. By using resistors in the range of $50 \mathrm{k} \Omega$, offset trim range is $\pm 3.3 \mathrm{mV}$.


Figure 26. Offset Voltage Nulling Circuit

## Programmable Gain Amplifier (PGA)

The combination of low noise, low input bias current, low input offset voltage, and low temperature drift make the AD8610 a perfect solution for programmable gain amplifiers. PGAs are often used immediately after sensors to increase the dynamic range of the measurement circuit. Historically, the large ON resistance of switches, combined with the large $\mathrm{I}_{\mathrm{B}}$ currents of amplifiers, created a large dc offset in PGAs. Recent and improved monolithic switches and amplifiers completely remove these problems. A PGA discrete circuit is shown in Figure 27. In Figure 27, when the 10 pA bias current of the AD8610 is dropped across the $(<5 \Omega) \mathrm{R}_{\mathrm{ON}}$ of the switch, it results in a negligible offset error.
When high precision resistors are used, as in the circuit of Figure 27, the error introduced by the PGA is within the $1 / 2$ LSB requirement for a 16 -bit system.


Figure 27. High Precision PGA

1. Room temperature error calculation due to $\mathrm{R}_{\mathrm{ON}}$ and $\mathrm{I}_{\mathrm{B}}$ :

$$
\begin{aligned}
& \Delta V_{O S}=I_{B} \times R_{O N}=2 \mathrm{pA} \times 5 \Omega=10 \mathrm{pV} \\
& \text { Total } \text { Offset }=A D 8610(\text { Offset })+\Delta V_{O S} \\
& \text { Total } \text { Offset }=\text { AD8610 }(\text { Offset_Trimmed })+\Delta V_{O S} \\
& \text { Total Offset }=5 \mu \mathrm{~V}+10 \mathrm{pV} \cong 5 \mu \mathrm{~V}
\end{aligned}
$$

2. Full temperature error calculation due to $\mathrm{R}_{\mathrm{ON}}$ and $\mathrm{I}_{\mathrm{B}}$ :

$$
\begin{aligned}
& \Delta V_{O S}\left(@ 85^{\circ} \mathrm{C}\right)=I_{B}\left(@ 85^{\circ} \mathrm{C}\right) \times R_{O N}\left(@ 85^{\circ} \mathrm{C}\right)= \\
& 250 \mathrm{pA} \times 15 \Omega=3.75 \mathrm{nV}
\end{aligned}
$$

3. Temperature coefficient of switch and AD8610/AD8620 combined is essentially the same as the $\mathrm{T}_{\mathrm{C}} \mathrm{V}_{\mathrm{OS}}$ of the AD 8610 :

$$
\begin{aligned}
& \Delta V_{O S} / \Delta T(\text { total })=\Delta V_{O S} / \Delta T(A D 8610)+\Delta V_{O S} / \Delta T\left(I_{B} \times R_{O N}\right) \\
& \Delta V_{O S} / \Delta T(\text { total })=0.5 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}+0.06 \mathrm{nV} /{ }^{\circ} \mathrm{C} \cong 0.5 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}
\end{aligned}
$$

## High Speed Instrumentation Amplifier (IN AMP)

The three op amp instrumentation amplifiers shown in Figure 28 can provide a range of gains from unity up to 1,000 or higher. The instrumentation amplifier configuration features high commonmode rejection, balanced differential inputs, and stable, accurately defined gain. Low input bias currents and fast settling are achieved with the JFET input AD8610/AD8620. Most instrumentation amplifiers cannot match the high frequency performance of this circuit. The circuit bandwidth is 25 MHz at a gain of 1 , and close to 5 MHz at a gain of 10 . Settling time for the entire circuit is 550 ns to $0.01 \%$ for a 10 V step (gain $=10$ ). Note that the resistors around the input pins need to be small enough in value so that the RC time constant they form in combination with stray circuit capacitance does not reduce circuit bandwidth.


Figure 28. High Speed Instrumentation Amplifier

## High Speed Filters

The four most popular configurations are Butterworth, Elliptical, Bessel, and Chebyshev. Each type has a response that is optimized for a given characteristic as shown in Table II.

In active filter applications using operational amplifiers, the dc accuracy of the amplifier is critical to optimal filter performance. The amplifier's offset voltage and bias current contribute to output error. Input offset voltage is passed by the filter, and may be amplified to produce excessive output offset. For low frequency applications requiring large value input resistors, bias and offset currents flowing through these resistors will also generate an offset voltage.
At higher frequencies, an amplifier's dynamic response must be carefully considered. In this case, slew rate, bandwidth, and openloop gain play a major role in amplifier selection. The slew rate must be both fast and symmetrical to minimize distortion. The amplifier's bandwidth, in conjunction with the filter's gain, will dictate the frequency response of the filter. The use of a high performance amplifier such as the AD8610/AD8620 will minimize both dc and ac errors in all active filter applications.

## Second-Order Low-Pass Filter

Figure 29 shows the AD8610 configured as a second-order Butterworth low-pass filter. With the values as shown, the corner frequency of the filter will be 1 MHz . The wide bandwidth of the AD8610/AD8620 allows a corner frequency up to tens of megaHertz. The following equations can be used for component selection:

$$
\begin{aligned}
& R 1=R 2=\text { User Selected }(\text { Typical Values: } 10 \mathrm{k} \Omega-100 \mathrm{k} \Omega) \\
& C 1=\frac{1.414}{(2 \pi)\left(f_{\text {CUTOFF }}\right)(R 1)} \\
& C 2=\frac{0.707}{(2 \pi)\left(f_{\text {CUTOFF }}\right)(R 1)}
\end{aligned}
$$

where $C 1$ and $C 2$ are in farads.


Figure 29. Second-Order Low-Pass Filter

Table II. Filter Types

| Type | Sensitivity | Overshoot | Phase | Amplitude (Pass Band) |
| :--- | :--- | :--- | :--- | :--- |
| Butterworth | Moderate | Good |  | Max Flat |
| Chebyshev | Good | Moderate | Nonlinear | Equal Ripple |
| Elliptical | Best | Poor |  | Equal Ripple |
| Bessel (Thompson) | Poor | Best | Linear |  |

## AD8610/AD8620

## High Speed, Low Noise Differential Driver

The AD8620 is a perfect candidate as a low noise differential driver for many popular ADCs. There are also other applications, such as balanced lines, that require differential drivers. The circuit of Figure 30 is a unique line driver widely used in industrial applications. With $\pm 13 \mathrm{~V}$ supplies, the line driver can deliver a differential signal of 23 V p -p into a $1 \mathrm{k} \Omega$ load. The high slew rate and wide bandwidth of the AD8620 combine to yield a full power bandwidth of 145 kHz while the low noise front end produces a referred-toinput noise voltage spectral density of $6 \mathrm{nV} / \sqrt{\mathrm{Hz}}$. The design is a transformerless, balanced transmission system where output common-mode rejection of noise is of paramount importance. Like the transformer-based design, either output can be shorted to ground for unbalanced line driver applications without changing the circuit gain of 1 . This allows the design to be easily set to noninverting, inverting, or differential operation.


Figure 30. Differential Driver

## OUTLINE DIMENSIONS

8-Lead Mini Small Outline Package [MSOP]
(RM-8)
Dimensions shown in millimeters


8-Lead Standard Small Outline Package [SOIC]
Narrow Body
(R-8)
Dimensions shown in millimeters and (inches)


CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN
AD8610/AD8620
Revision History
Location Page
2/04-Data Sheet changed from REV. C to REV. D.
Changes to SPECIFICATIONS ..... 2
Changes to ORDERING GUIDE ..... 4
Updated OUTLINE DIMENSIONS ..... 17
10/02—Data Sheet changed from REV. B to REV. C.
Updated ORDERING GUIDE ..... 4
Edits to Figure 15 ..... 12
Updated OUTLINE DIMENSIONS ..... 16
5/02-Data Sheet changed from REV. A to REV. B.
Addition of part number AD8620 ..... Universal
Addition of 8-Lead SOIC (R-8 Suffix) Drawing ..... 1
Changes to GENERAL DESCRIPTION ..... 1
Additions to SPECIFICATIONS ..... 2
Change to ELECTRICAL SPECIFICATIONS ..... 3
Additions to ORDERING GUIDE ..... 4
Replace TPC 29 ..... 8
Add Channel Separation Test Circuit Figure ..... 9
Add Channel Separation Graph ..... 9
Changes to Figure 26 ..... 15
Addition of High-Speed, Low Noise Differential Driver section ..... 16
Addition of Figure 30 ..... 16


[^0]:    Specifications subject to change without notice.

[^1]:    Specifications subject to change without notice.

[^2]:    *Pb-free part

